- Members of the Texas Instruments Widebus+<sup>™</sup> Family
- State-of-the-Art *EPIC-*II*B* ™ BiCMOS Design Significantly Reduces Power Dissipation
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17

- Typical V<sub>OLP</sub> (Output Ground Bounce)
  < 0.8 V at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C
- Distributed V<sub>CC</sub> and GND Pin Configuration Minimizes High-Speed Switching Noise
- High-Drive Outputs (-32-mA I<sub>OH</sub>, 64-mA I<sub>OL</sub>)
- Bus-Hold Inputs Eliminate the Need for External Pullup Resistors
- Packaged in 100-Pin Plastic Shrink Quad Flat Pack (SQFP) With 14 × 14-mm Package Body Using 0.5-mm Lead Pitch



Widebus+ and EPIC-IIB are trademarks of Texas Instruments Incorporated.



SCBS460 – JUNE 1992–REVISED OCTOBER 1992

#### description

The 'ABT32373 is a 32-bit (quad 8-bit) transceiver with D-type latches and 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. It is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers. The device can be used as four 8-bit transceivers, two 16-bit transceivers, or one 32-bit transceiver. It allows data transmission from the A bus to the B bus or from the B bus to the A bus depending upon the logic level at the output-enable inputs.

The output-enable (OEAB or OEBA) inputs do not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver (A to B). OE should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver (B to A).

Active bus-hold circuitry is provided to hold unused or floating inputs at a valid logic level.

The SN54ABT32373 is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to  $125^{\circ}$ C. The SN74ABT32373 is characterized for operation from  $-40^{\circ}$ C to  $85^{\circ}$ C.

(each transceiver)									
	INPUTS		OUTPUT						
OEAB	LEAB	В							
L	Н	Н	Н						
L	Н	L	L						
L	L	Х	Q <sub>0</sub>						
Н	Х	Х	Z						

## FUNCTION TABLE<sup>†</sup>

<sup>+</sup> A-to-B data flow is shown. B-to-A data flow is similar but uses OEBA and LEBA.



SCBS460 - JUNE 1992-REVISED OCTOBER 1992





SCBS460 – JUNE 1992–REVISED OCTOBER 1992

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

	-
Supply voltage range, V <sub>CC</sub>	–0.5 V to 7 V
Input voltage range, VI (except I/O ports) (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state or power-off state, $V_O$	–0.5 V to 5.5 V
Current into any output in the low state, IO: SN54ABT32373	96 mA
SN74ABT32373	128 mA
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	–18 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)	–50 mA
Storage temperature range	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

### recommended operating conditions

					SN74ABT32373		UNIT
			MIN	MAX	MIN	MAX	UNIT
VCC	Supply voltage		4.5	5.5	4.5	5.5	V
VIH	High-level input voltage		2		2		V
VIL	Low-level input voltage			0.8		0.8	V
VI	Input voltage		0	VCC	0	VCC	V
IOH	High-level output current			-24		-32	mA
IOL	Low-level output current			48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		10		10	ns/V
TA	Operating free-air temperature		-55	125	-40	85	°C



SCBS460 - JUNE 1992-REVISED OCTOBER 1992

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54ABT32373			SN7					
		TEST CONDITIONS			MIN	TYP <sup>†</sup>	MAX	MIN	TYP <sup>†</sup>	MAX	UNIT	
VIK		V <sub>CC</sub> = 4.5 V,	lj = –18 mA				-1.2			-1.2	V	
Vou		V <sub>CC</sub> = 4.5 V,	IOH = -3 mA		2.5			2.5				
		$V_{CC} = 5 V$ , $I_{OH} = -3 mA$ $V_{CC} = 4.5 V$ , $I_{OH} = -24 mA$			3			3			.,	
					2						V	
		V <sub>CC</sub> = 4.5 V,	IOH = -32 mA					2				
		V <sub>CC</sub> = 4.5 V,	I <sub>OL</sub> = 48 mA				0.55			0.55		
VOL		V <sub>CC</sub> = 4.5 V,	I <sub>OL</sub> = 64 mA							0.55	V	
	Control inputs	$V_{CC} = 5.5 \text{ V},  V_{I} = V_{CC} \text{ or GND}$								±1		
Ι	A or B ports			D						±100	μA	
		V <sub>CC</sub> = 4.5 V,	V <sub>I</sub> = 0.8 V					100				
<sup>I</sup> hold	A or B ports	$V_{CC} = 4.5 V, V_{I} = 2 V$						-100			μA	
<sup>I</sup> OZH <sup>‡</sup>		V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 2.7 V							50	μA		
I <sub>OZL</sub> ‡		$V_{CC} = 5.5 \text{ V},  V_{O} = 0.5 \text{ V}$								-50	μA	
IOFF		$V_{CC} = 0$ , $V_{I}$ or $V_{O} \le 4.5$ V								±100	μA	
ICEX	-	V <sub>CC</sub> = 5.5 V,	V <sub>O</sub> = 5.5 V	Outputs high						50	μA	
IO§		V <sub>CC</sub> = 5.5 V,	Vo = 2.5 V	•				-50	-100	-180	mA	
		$V_{CC} = 5.5 \text{ V},  I_O = 0,$ $V_I = V_{CC} \text{ or GND}$		Outputs high						2		
ICC				Outputs low						5	mA	
				Outputs disabled						0.5		
∆ICC <sup>¶</sup>		V <sub>CC</sub> = 5.5 V, Other inputs at V	One input at 3. V <sub>CC</sub> or GND	4 V,						1	mA	
Ci	Control inputs	V <sub>I</sub> = 2.5 V or 0.5 V								pF		
Cio	A or B ports	V <sub>O</sub> = 2.5 V or 0.5 V									pF	

<sup>†</sup> All typical values are at V<sub>CC</sub> = 5 V,  $T_A = 25^{\circ}$ C.

<sup>‡</sup> The parameters I<sub>OZH</sub> and I<sub>OZL</sub> include the input leakage current.

§ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

This is the increase in supply current for each input that is at the specified TTL voltage level rather than V<sub>CC</sub> or GND.

# timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

		SN54AB	SN54ABT32373 MIN MAX		SN74ABT32373		
		MIN			MAX	UNIT	
tw	Pulse duration, LE high					ns	
t <sub>su</sub>	Setup time, data before LE $\downarrow$					ns	
th	Hold time, data after LE $\downarrow$					ns	



SCBS460 – JUNE 1992–REVISED OCTOBER 1992

switching characteristics over recommended ranges of supply voltage and operating free-air temperature,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	SN54ABT32373			SN74	UNIT		
(INPUT)		(OUTPUT)	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
<sup>t</sup> PLH	A or B	A or B B or A							
<sup>t</sup> PHL	AUD	BOIA							ns
<sup>t</sup> PLH	LEAB or LEBA	AB or LEBA B or A							ns
<sup>t</sup> PHL		BOIA							115
<sup>t</sup> PZH	OEAB or OEBA	B or A							ns
<sup>t</sup> PZL		BOIA							115
<sup>t</sup> PHZ	OEAB or OEBA	B or A							ns
<sup>t</sup> PLZ	OEND OF OEDA	BOR							113



SCBS460 – JUNE 1992–REVISED OCTOBER 1992



### PARAMETER MEASUREMENT INFORMATION

- NOTES: A. Cl includes probe and jig capacitance.
  - B. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>0</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns, t<sub>f</sub>  $\leq$  2.5 ns. C. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.
  - Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - D. The outputs are measured one at a time with one transition per measurement.

### Figure 1. Load Circuit and Voltage Waveforms



#### **IMPORTANT NOTICE**

Texas Instruments (TI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

TI warrants performance of its semiconductor products and related software to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Certain applications using semiconductor products may involve potential risks of death, personal injury, or severe property or environmental damage ("Critical Applications").

TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS.

Inclusion of TI products in such applications is understood to be fully at the risk of the customer. Use of TI products in such applications requires the written approval of an appropriate TI officer. Questions concerning potential risk applications should be directed to TI through a local SC sales office.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards should be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor does TI warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.

Copyright © 1996, Texas Instruments Incorporated